

FGW25N120W

Discrete IGBT

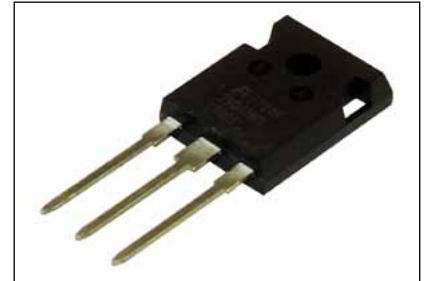
Discrete IGBT (High-Speed W series) 1200V / 25A

■ Features

- Low power loss
- Low switching surge and noise
- High reliability, high ruggedness (RBSOA, SCSOA etc.)

■ Applications

- Uninterruptible power supply
- PV Power conditioner
- Inverter welding machine



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at $T_c=25^\circ\text{C}$ unless otherwise specified)

Items	Symbols	Characteristics	Units	Remarks
Collector-Emitter Voltage	V_{CES}	1200	V	
Gate-Emitter Voltage	V_{GES}	± 20	V	
DC Collector Current	$I_{C@25}$	40	A	$T_c=25^\circ\text{C}, T_j=150^\circ\text{C}$
	$I_{C@100}$	25	A	$T_c=100^\circ\text{C}, T_j=150^\circ\text{C}$
Pulsed Collector Current	I_{CP}	100	A	Note *1
Turn-Off Safe Operating Area	-	100	A	$V_{CE} \leq 1200\text{V}, T_j \leq 175^\circ\text{C}$
Short Circuit Withstand Time	t_{SC}	5	μs	$V_{CC} \leq 600\text{V}, V_{GE} = 15\text{V}$ $T_j \leq 150^\circ\text{C}$
IGBT Max. Power Dissipation	P_D	270	W	$T_c=25^\circ\text{C}$
Operating Junction Temperature	T_j	-40 ~ +175	$^\circ\text{C}$	
Storage Temperature	T_{sig}	-55 ~ +175	$^\circ\text{C}$	

Note *1 : Pulse width limited by T_{jmax} .

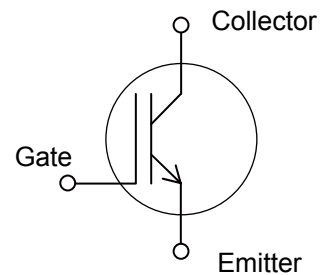
● Electrical characteristics (at $T_j=25^\circ\text{C}$ unless otherwise specified)

Description	Symbols	Conditions	Characteristics			Units	
			min.	typ.	max.		
Zero Gate Voltage Collector Current	I_{CES}	$V_{CE} = 1200\text{V}, V_{GE} = 0\text{V}$	$T_j=25^\circ\text{C}$	-	-	250	μA
			$T_j=175^\circ\text{C}$	-	-	2	mA
Gate-Emitter Leakage Current	I_{GES}	$V_{CE} = 0\text{V}, V_{GE} = \pm 20\text{V}$		-	-	200	nA
Gate-Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = +20\text{V}, I_C = 25\text{mA}$		5.0	6.0	7.0	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_{GE} = +15\text{V}, I_C = 25\text{A}$	$T_j=25^\circ\text{C}$	1.4	2.0	2.6	V
			$T_j=175^\circ\text{C}$	-	2.6	-	
Input Capacitance	C_{ies}	$V_{CE}=25\text{V}$		825	1650	2475	pF
Output Capacitance	C_{oes}	$V_{GE}=0\text{V}$		37	75	113	
Reverse Transfer Capacitance	C_{res}	$f=1\text{MHz}$		11	23	35	
Gate Charge	Q_G	$V_{CC} = 400\text{V}$ $I_C = 25\text{A}$ $V_{GE} = 15\text{V}$		40	80	120	nC
Turn-On Delay Time	$t_{d(on)}$	$T_j = 25^\circ\text{C}$		14	28	42	ns
Rise Time	t_r	$V_{CC} = 600\text{V}$		16	32	48	
Turn-Off Delay Time	$t_{d(off)}$	$I_C = 25\text{A}$		61	122	183	
Fall Time	t_f	$V_{GE} = 15\text{V}$		16	32	48	
Turn-On Energy	E_{on}	$R_G = 10\Omega$ $L = 500\mu\text{H}$		0.45	0.9	1.35	
Turn-Off Energy	E_{off}	Energy loss include "tail" and FWD (FDRW12S120J) reverse recovery.		0.65	1.3	1.95	mJ
Turn-On Delay Time	$t_{d(on)}$	$T_j = 150^\circ\text{C}$		14	28	42	ns
Rise Time	t_r	$V_{CC} = 600\text{V}$		16	32	48	
Turn-Off Delay Time	$t_{d(off)}$	$I_C = 25\text{A}$		89	178	267	
Fall Time	t_f	$V_{GE} = 15\text{V}$		30	60	90	
Turn-On Energy	E_{on}	$R_G = 10\Omega$ $L = 500\mu\text{H}$		0.75	1.5	2.25	
Turn-Off Energy	E_{off}	Energy loss include "tail" and FWD (FDRW12S120J) reverse recovery.		1.1	2.2	3.3	mJ

● Thermal resistance characteristics

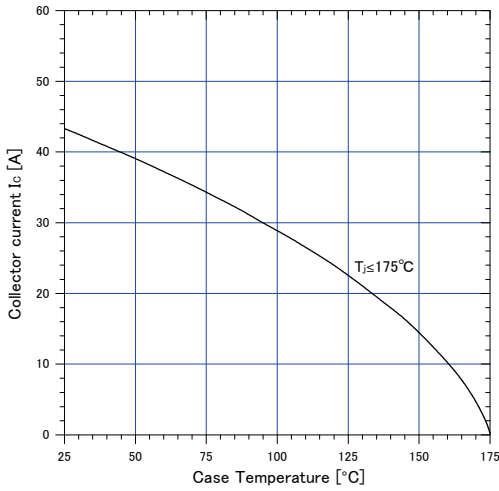
Items	Symbols	Conditions	Characteristics			Units
			min.	typ.	max.	
Thermal Resistance, Junction-Ambient	$R_{th(j-a)}$	-	-	-	50	$^\circ\text{C/W}$
Thermal Resistance, Junction to Case	$R_{th(j-c)}_{IGBT}$	-	-	-	0.546	$^\circ\text{C/W}$

■ Equivalent circuit

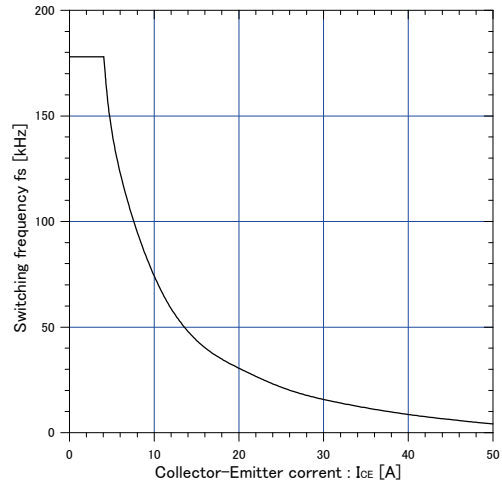


■ Characteristics (Representative)

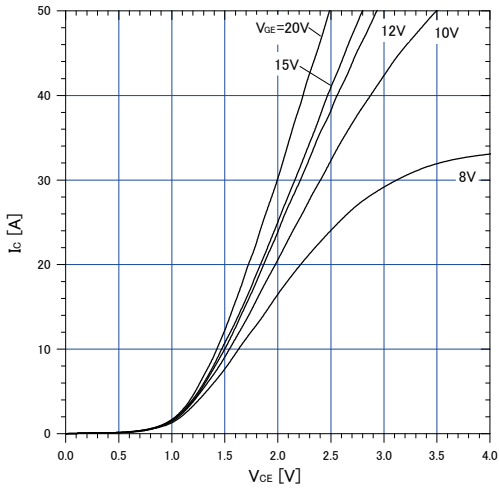
Graph.1
DC Collector Current vs T_c
 $V_{GE} \geq +15V, T_j \leq 175^\circ C$



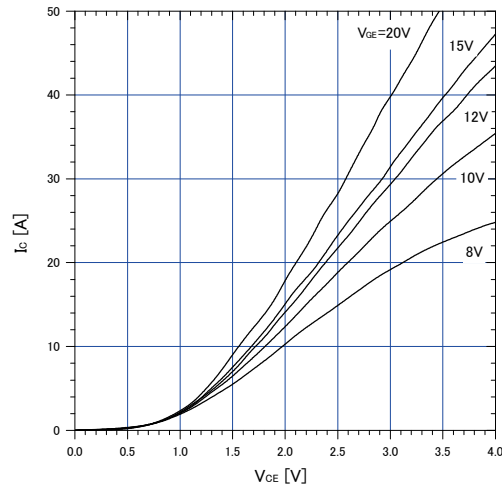
Graph.2
Collector Current vs. switching frequency
 $V_{GE} = +15V, T_c \leq 175^\circ C, V_{CC} = 600V, D = 0.5, R_G = 10\Omega, T_c = 100^\circ C$



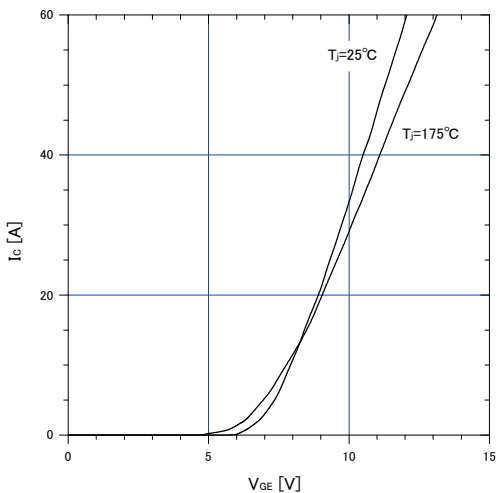
Graph.3
Typical Output Characteristics ($V_{CE}-I_c$)
 $T_j = 25^\circ C$



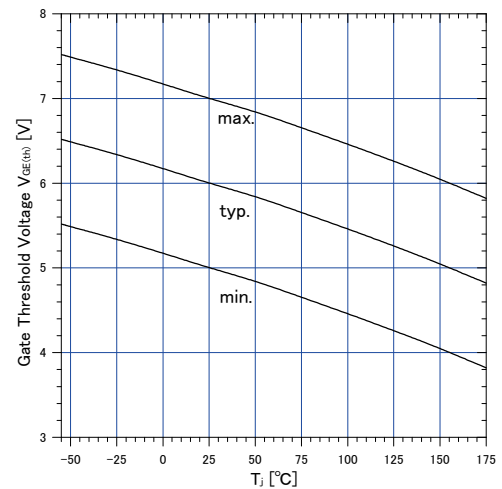
Graph.4
Typical Output Characteristics ($V_{CE}-I_c$)
 $T_j = 175^\circ C$



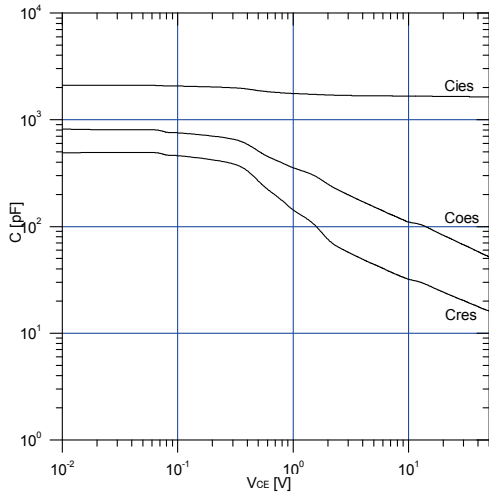
Graph.5
Typical Transfer Characteristics
 $V_{GE} = +15V$



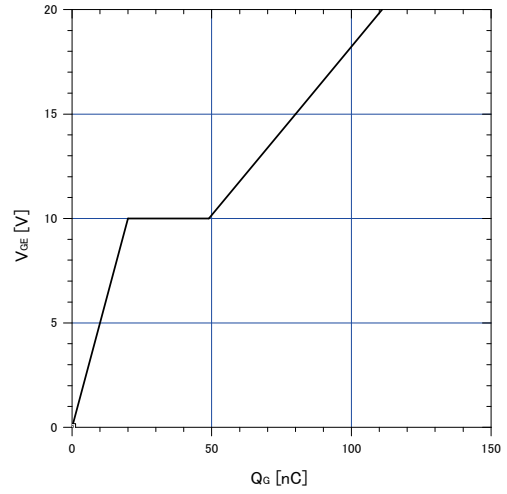
Graph.6
Gate Threshold Voltage vs. T_j
 $I_c = 25mA, V_{CE} = 20V$



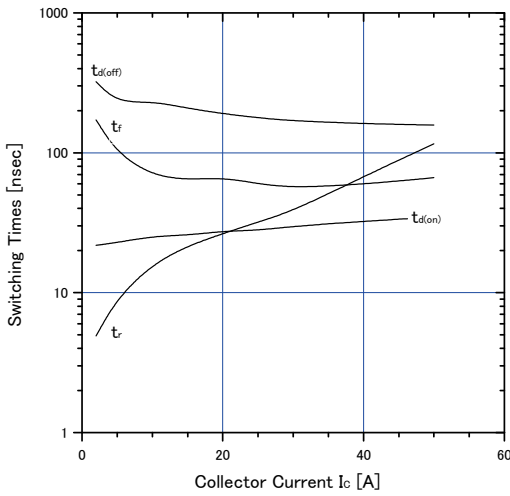
Graph.7
 Typical Capacitance
 $V_{GE}=0V, f=1MHz, T_J=25^\circ C$



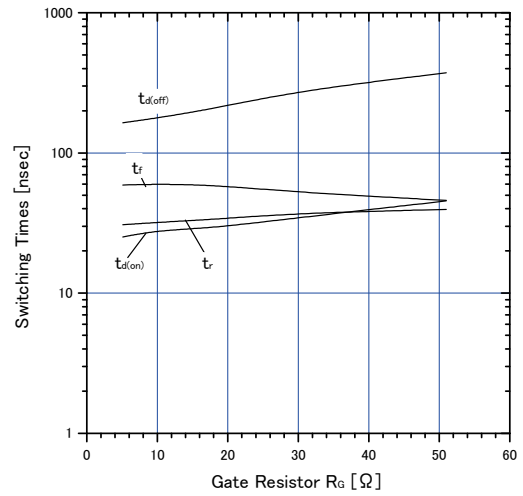
Graph.8
 Typical Gate Charge
 $V_{CC}=600V, I_c=25A, T_J=25^\circ C$



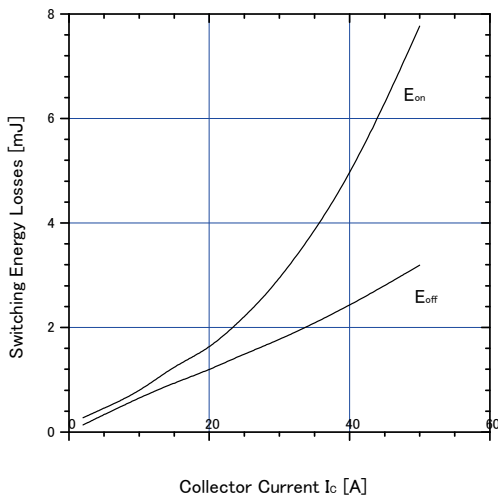
Graph.9
 Typical switching time vs. I_c
 $T_J=175^\circ C, V_{CC}=600V, L=500\mu H$
 $V_{GE}=15V, R_G=10\Omega$



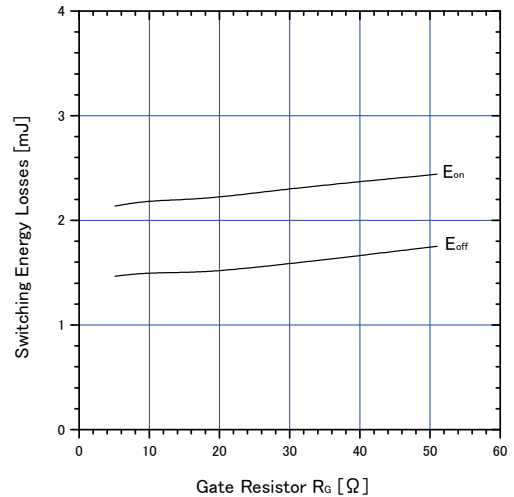
Graph.10
 Typical switching time vs. R_G
 $T_J=175^\circ C, V_{CC}=600V, I_c=25A, L=500\mu H$
 $V_{GE}=15V$



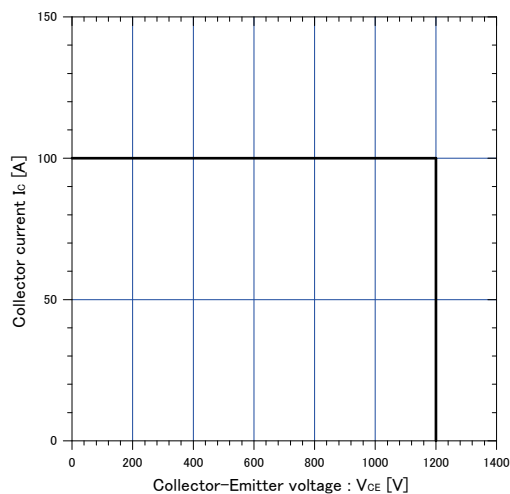
Graph.11
 Typical switching losses vs. I_c
 $T_J=175^\circ C, V_{CC}=600V, L=500\mu H$
 $V_{GE}=15V, R_G=10\Omega$



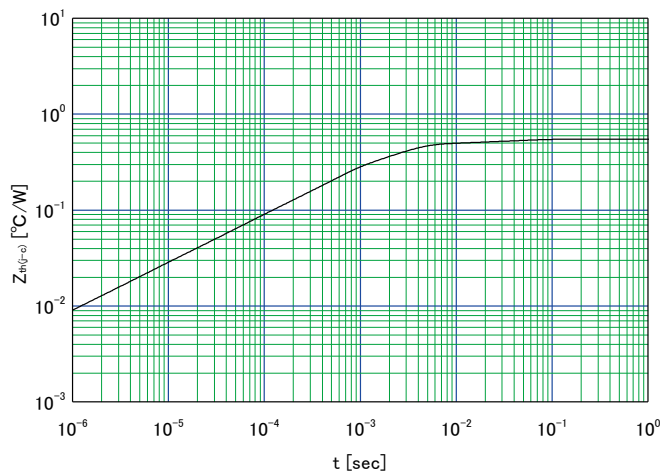
Graph.12
 Typical switching losses vs. R_G
 $T_J=175^\circ C, V_{CC}=600V, I_c=40A, L=500\mu H$
 $V_{GE}=15V$



Graph.13
Reverse biased Safe Operating Area
 $T_{\leq 175^{\circ}\text{C}}, V_{\text{GE}} = +15\text{V}/0\text{V}, R_{\text{G}} = 10\Omega$

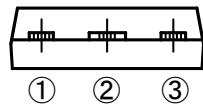
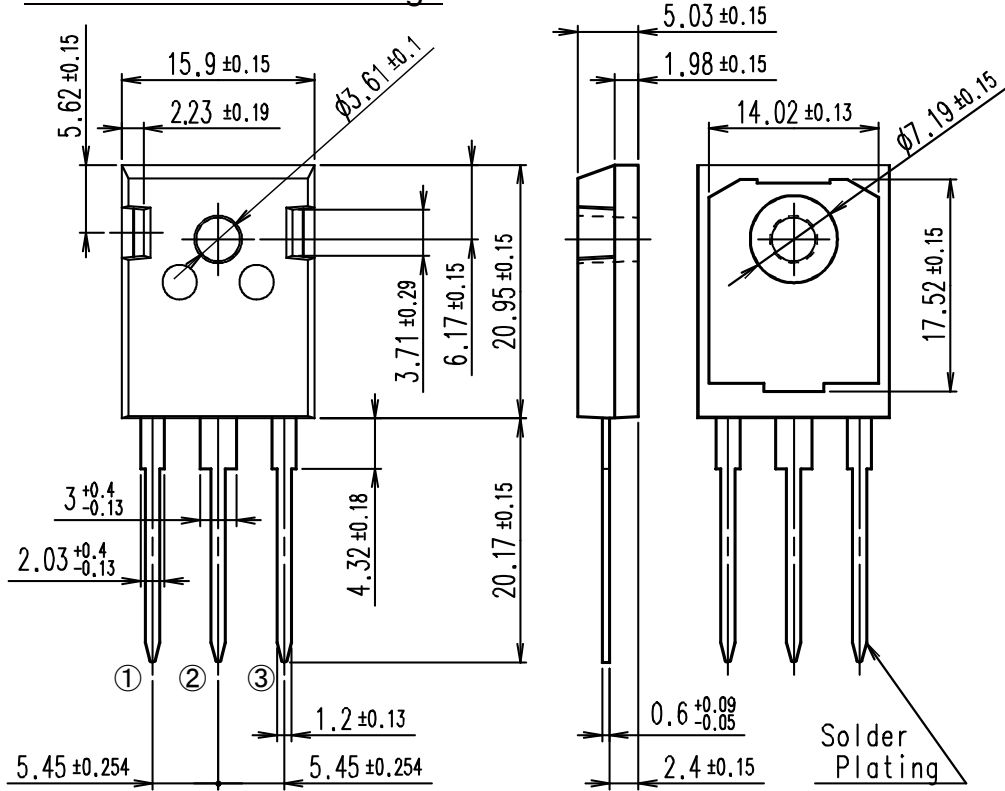


Graph.14
Transient thermal resistance



■ Outline Drawings, mm

Outview : TO-247 Package



DIMENSIONS ARE IN MILLIMETERS.

WARNING

1. This Catalog contains the product specifications, characteristics, data, materials, and structures as of June 2015. The contents are subject to change without notice for specification changes or other reasons. When using a product listed in this Catalog, be sure to obtain the latest specifications.
2. All applications described in this Catalog exemplify the use of Fuji's products for your reference only. No right or license, either express or implied, under any patent, copyright, trade secret or other intellectual property right owned by Fuji Electric Co., Ltd. is (or shall be deemed) granted. Fuji Electric Co., Ltd. makes no representation or warranty, whether express or implied, relating to the infringement or alleged infringement of other's intellectual property rights which may arise from the use of the applications described herein.
3. Although Fuji Electric Co., Ltd. is enhancing product quality and reliability, a small percentage of semiconductor products may become faulty. When using Fuji Electric semiconductor products in your equipment, you are requested to take adequate safety measures to prevent the equipment from causing a physical injury, fire, or other problem if any of the products become faulty. It is recommended to make your design failsafe, flame retardant, and free of malfunction.
4. The products introduced in this Catalog are intended for use in the following electronic and electrical equipment which has normal reliability requirements.
 - Computers
 - OA equipment
 - Communications equipment (terminal devices)
 - Measurement equipment
 - Machine tools
 - Audiovisual equipment
 - Electrical home appliances
 - Personal equipment
 - Industrial robots etc.
5. If you need to use a product in this Catalog for equipment requiring higher reliability than normal, such as for the equipment listed below, it is imperative to contact Fuji Electric Co., Ltd. to obtain prior approval. When using these products for such equipment, take adequate measures such as a backup system to prevent the equipment from malfunctioning even if a Fuji's product incorporated in the equipment becomes faulty.
 - Transportation equipment (mounted on cars and ships)
 - Trunk communications equipment
 - Traffic-signal control equipment
 - Gas leakage detectors with an auto-shut-off feature
 - Emergency equipment for responding to disasters and anti-burglary devices
 - Safety devices
 - Medical equipment
6. Do not use products in this Catalog for the equipment requiring strict reliability such as the following and equivalents to strategic equipment (without limitation).
 - Space equipment
 - Aeronautic equipment
 - Nuclear control equipment
 - Submarine repeater equipment
7. Copyright ©1996-2015 by Fuji Electric Co., Ltd. All rights reserved.
No part of this Catalog may be reproduced in any form or by any means without the express permission of Fuji Electric Co., Ltd.
8. If you have any question about any portion in this Catalog, ask Fuji Electric Co., Ltd. or its sales agents before using the product. Neither Fuji Electric Co., Ltd. nor its agents shall be liable for any injury caused by any use of the products not in accordance with instructions set forth herein.

Technical Information

IGBT Modules

- Please refer to URLs below for further information about products, application manuals and design support.
- 关于本规格书中没有记载的产品信息，应用手册，技术信息等，请参考以下链接。
- 本データシートに記載されていない製品情報，アプリケーションマニュアル，デザインサポートは以下の URL をご参照下さい。

FUJI ELECTRIC Power Semiconductor WEB site

日本	www.fujielectric.co.jp/products/semiconductor/
Global	www.fujielectric.com/products/semiconductor/
中国	www.fujielectric.com.cn/products/semiconductor/
Europe	www.fujielectric-europe.com/en/power_semiconductor/
North America	www.americas.fujielectric.com/products/semiconductors/

Information

日本

1 半導体総合カタログ	www.fujielectric.co.jp/products/semiconductor/catalog/
2 製品情報	www.fujielectric.co.jp/products/semiconductor/model/
3 アプリケーションマニュアル	www.fujielectric.co.jp/products/semiconductor/model/igbt/application/
4 デザインサポート	www.fujielectric.co.jp/products/semiconductor/model/igbt/technical/
5 マウンティングインストラクション	www.fujielectric.co.jp/products/semiconductor/model/igbt/mounting/
6 IGBT 損失シミュレーションソフト	www.fujielectric.co.jp/products/semiconductor/model/igbt/simulation/
7 富士電機技報	www.fujielectric.co.jp/products/semiconductor/journal/
8 製品のお問い合わせ	www.fujielectric.co.jp/products/semiconductor/contact/
9 改廃のお知らせ	www.fujielectric.co.jp/products/semiconductor/discontinued/

Global

1 Semiconductors General Catalog	www.fujielectric.com/products/semiconductor/catalog/
2 Product Information	www.fujielectric.com/products/semiconductor/model/
3 Application Manuals	www.fujielectric.com/products/semiconductor/model/igbt/application/
4 Design Support	www.fujielectric.com/products/semiconductor/model/igbt/technical/
5 Mounting Instructions	www.fujielectric.com/products/semiconductor/model/igbt/mounting/
6 IGBT Loss Simulation Software	www.fujielectric.com/products/semiconductor/model/igbt/simulation/
7 Fuji Electric Journal	www.fujielectric.com/products/semiconductor/journal/
8 Contact	www.fujielectric.com/contact/
9 Revised and discontinued product information	www.fujielectric.com/products/semiconductor/discontinued/

中国

1 半导体综合目录	www.fujielectric.com.cn/products/semiconductor/catalog/
2 产品信息	www.fujielectric.com.cn/products/semiconductor/model/
3 应用手册	www.fujielectric.com.cn/products/semiconductor/model/igbt/application/
4 技术信息	www.fujielectric.com.cn/products/semiconductor/model/igbt/technical/
5 安装说明书	www.fujielectric.com.cn/products/semiconductor/model/igbt/mounting/
6 IGBT 损耗模拟软件	www.fujielectric.com.cn/products/semiconductor/model/igbt/simulation/
7 富士电机技报	www.fujielectric.com.cn/products/semiconductor/journal/
8 产品咨询	www.fujielectric.com/contact/
9 产品更改和停产信息	www.fujielectric.com.cn/products/semiconductor/discontinued/